

# Photoelectrochemical solar cells based on SnO<sub>2</sub> nanocrystalline films

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**Abstract:** Dye-sensitized solar cells (DSSCs) fabricated using nanocrystalline SnO<sub>2</sub> films sensitized by the Ru(dcbpy)(NCS)<sub>2</sub> dye (N3) were compared to the corresponding nanocrystalline titania cells. Although the light-to-power energy conversion efficiency of SnO<sub>2</sub> cells is low with respect to the nc-TiO<sub>2</sub> DSSCs, their general characteristics are similar. The influence of the addition of 4-tert-butylpyridine (4TBP) or acetic acid to the electrolyte was investigated. 4TBP increased the cell's open-circuit voltage and stability. Raman spectroscopy confirmed the presence of new vibration bands; their intensity depends on the additives and characterizes the amount of tri-iodides at the photoactive interface, as well the complex formed between dye and iodide. To cite this article: N. Nang Dinh et al., C. R. Chimie 9 (2006). © 2005 Académie des sciences.

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References:

- Tennakone, K., Bandaranayake, P.K.M., Jayaweera, P.V.V., Konno, A., Kumara, G.R.R.A., (2002) Physica E, 14, p. 190. , (Amsterdam)
- Kamat, P.V., Bedja, I., Hotchandani, S., Patterson, L.K., (1996) J. Phys. Chem., 100, p. 4900
- Bandara, J., Tennakone, K., Jayatilaka, P.P.B., (2002) Chemosphere, 49, p. 439
- Fungo, F., Otero, L.A., Sereno, L., Silber, J.J., Durantidi, E.N., (2000) J. Mater. Chem., 10, p. 645
- Nasr, C., Kamat, P., Hotchandani, S., (1998) J. Phys. Chem. B, 102, p. 10047
- Hara, K., Horiguchi, T., Kinoshita, T., Sayama, K., Sugihara, H., Arakawa, H., (2000) Sol. Energ. Mat. Sol. C., 64, p. 115
- Srivastava, D.N., Chappel, S., Palchik, O., Zaban, A., Gedanken, A., (2002) Langmuir, 18, p. 4160
- Ferrere, S., Zaban, A., Gregg, B.A., (1997) J. Phys. Chem. B, 101, p. 4490
- Tian, H., Liu, P.-H., Meng, F.-S., Gao, E., Cai, S., (2001) Synthetic Met., 121, p. 1557
- Chappel, S., Zaban, A., (2002) Sol. Energ. Mat. Sol. C., 71, p. 141
- Kay, A., Grätzel, M., (2002) Chem. Mater., 14, p. 2930
- Nazeeruddin, M.K., Pechy, P., Renouard, T., Zakeeruddin, S.M., Humphry-Baker, R., Comte, P., Liska, P., Grätzel, M., (2001) J. Am. Chem. Soc., 123, p. 1613
- Huang, S.Y., Schlichthörl, G., Nozik, A.J., Grätzel, M., Frank, A.J., (1997) J. Phys. Chem. B, 101, p. 2576
- Kang, T.S., Chun, K.H., Hong, J., Moon, S.H., Kim, K.J., (2000) J. Electrochem. Soc., 147, p. 3049
- Bernard, M.C., Cachet, H., Falaras, P., Hugot-Le Goff, A., Kalbac, M., Lukes, I., Oanh, N.T., Arabatzis, I., (2003) J. Electrochem. Soc., 150, pp. E155
- Stergiopoulos, T., Bernard, M.C., Hugot-Le Goff, A., Falaras, P., (2004) Coord. Chem. Rev., , (in press)
- Stergiopoulos, T., Bernard, M.C., Goff, A.H.-L., Falaras, P., (2003) Abstracts 203th Electrochem. Soc. Meeting, Paris
- Hugot-Le Goff, A., Joiret, S., Falaras, P., (1999) J. Phys. Chem. B, 103, p. 9569
- Greijer, H., Lindgren, J., Hagfeldt, A., (2001) J. Phys. Chem. B, 105, p. 6314
- Greijer Agrell, H., Lindgren, J., Hagfeldt, A., (2003) Sol. Energy, 75, p. 169

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